

High-Speed USB 2.0 480Mbps Switch

General Description

The ET7228 is a 2CH single-pole/double-throw (SPDT) switches. Their wide bandwidth and low bit-to-bit skew allow them to pass high-speed differential signals with good signal integrity.

Each switch is bidirectional and offers little or no attenuation of the high-speed signals at the outputs. Industry-leading advantages include a propagation delay of less than 250 ps, resulting from its low channel resistance and low I/O capacitance. Their high channel-to-channel crosstalk rejection results in minimal noise interference. Their bandwidth is wide enough to pass High-Speed USB 2.0 differential signals (480 Mb/s).

ET7228 is offered in a QFN10L package.

Features

- R_{ON} is typically 6.0 Ω @ V_{CC} = 3.3 V
- Low Bit-to-Bit skew is typically 50 ps
- Low current consumption is 1.0 µA typical
- Near-zero propagation delay is typical 250 ps
- Channel on-capacitance is 4.0 pF typical
- V_{CC} operating range from 1.65 V to 4.5 V
- Part No. and package

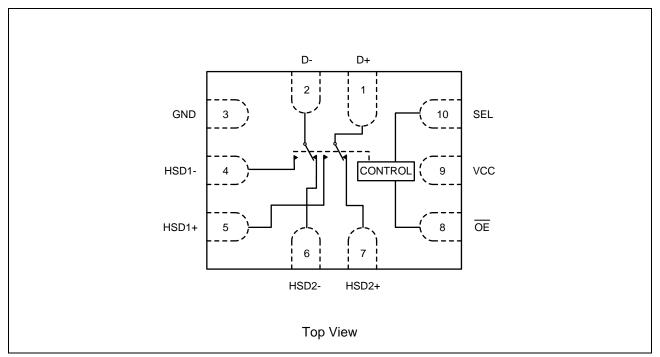
Part No.	Package	MSL
ET7228	QFN10L(1.8 mm×1.4 mm)	Level 1

Applications

- Differential Signal Data Routing
- USB 2.0 Signal Routing

ET7228

Pin Configuration



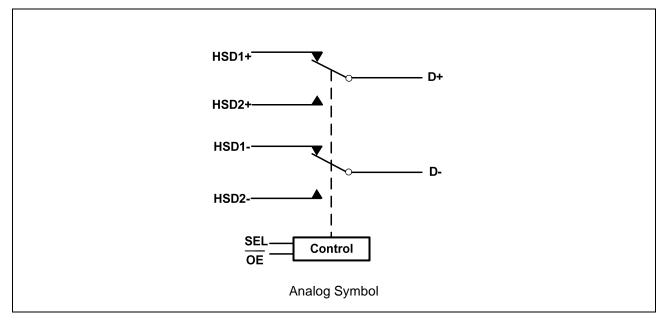
Pin Function

Pin No.	Pin Name	Pin Function
1	D+	Data Ports
2	D-	Data Ports
3	GND	Ground
4	HSD1-	Data Ports
5	HSD1+	Data Ports
6	HSD2-	Data Ports
7	HSD2+	Data Ports
8	ŌĒ	Output Enable
9	VCC	Power supply
10	SEL	Select Input

Truth Table

OE	SEL	HSD1+ to D+, HSD1- to D-	HSD2+ to D+, HSD2- to D-
1	Х	OFF	OFF
0	0	ON	OFF
0	1	OFF	ON

Analog Symbol



Symbol	Pins	Parameters	Value	Unit	
Vcc	VCC	Positive DC Supply Voltage	-0.5 to +6.0	V	
VIS	HSD1+,HSD1-,HSD2+,HSD2-	Analog Signal Voltage	-0.5 to V_{CC}	V	
VIS	D+,D-	-0.5 to +5.		v	
Vin	OE	Control Input Voltage	-0.5 to +6.0	V	
Icc	VCC	Positive DC Supply Current	50	mA	
lia agu	HSD1+,HSD1-,HSD2+,HSD2-	Analog Signal Continuous	±100	mA	
IIS_CON	D+,D-	Current	± 100	IIIA	
IIS_PK	HSD1+,HSD1-,HSD2+,HSD2-	Analog Signal Continuous	±150	mA	
115_PK	D+,D-	Current 10% Duty Cycle	± 150		
lın	ŌĒ	Control Input Current	±20	mA	
TJ		Junction Temperature Range	-40 to +150	°C	
Tstg		Storage Temperature	-65 to +150	°C	

Absolute Maximum Ratings

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Symbol Pins **Parameter** Min Max Unit VCC Positive DC Supply Voltage 4.5 V Vcc 1.65 HSD1+,HSD1-,HSD2+,HSD2-GND Vcc V Vis Analog Signal Voltage D+,D-GND 4.5 VIN ŌĒ Digital Select Input Voltage GND V_{CC} V °C -40 +85 T_A Operating Temperature Range

Recommended Operating Conditions

Minimum and maximum values are guaranteed through test or design across the Recommended Operating Conditions, where applicable. Typical values are listed for guidance only and are based on the particular conditions listed for section, where applicable. These conditions are valid for all values found in the characteristics tables unless otherwise specified in the test conditions.

DC Electrical Characteristics

Control Input (Typical: $T_A = 25 \text{ °C}$, $V_{CC} = 3.3 \text{ V}$)

Symbol	Pins	Parameter	Test	V., ()()	-40	°C to +8	5°C	unit
Symbol	ndoi Pins Paramete		Conditions	V _{CC} (V)	Min	Тур	Max	unit
	SEL	Control Input High		2.7	1.0			
VIH	OE	Voltage ⁽¹⁾		3.4	1.1	-	-	V
	ÛE	E Voltage("		4.2	1.12			
		Control Input Low		2.7			0.4	
VIL		Control Input Low Voltage ⁽¹⁾		3.4	-		0.4	V
	ÛE	vollage		4.2			0.5	
L.		Control Input		1 65 1 5			.1.0	
lin		Leakage Current	$0 \le V_{IS} \le V_{CC}$	1.65 ~ 4.5	-	-	±1.0	μA

Note1: V_{IH} level is recommended to be consistent with V_{CC} and V_{IL} level is GND to reduce I_{CC} current.

Supply And Leakage Current	(Typical: $T_A = 25 \text{ °C}$, $V_{CC} = 3.3 \text{ V}$,	$OE = V_{CC}$ or GND, $S = V_{CC}$ or GND)

Symbol	Symbol Pins Parameter		Test Conditions		-40°C to	o +85°C	unit
Symbol	FIIIS	Parameter	Test Conditions	V _{CC} (V)	Min	Max	umi
Icc	V _{cc}	Quiescent Supply Current	$V_{IS} = V_{CC} \text{ or } GND;$ $I_{OUT} = 0A$	1.65 ~ 4.5	-	1.0	μA
Ісст	Vcc	Increase in Icc per Control Voltage	V _{IN} = 2.6V	3.6	-	10	μA
loz	HSD1+ HSD1- HSD2+ HSD2-	OFF Stage Leakage Current	$0 \le V_{IS} \le V_{CC}$	1.65 ~ 4.5	-	±1.0	μΑ
IOFF	D+, D-	Power OFF Leakage Current	$0 \le V_{IS} \le 4.5 V$	0	-	±1.0	μA

Symbol	Parameter	Test Conditions		-40	-40°C to +85°C		
Symbol	Farameter	Test Conditions	V _{cc} (V)	Min	Тур	Max	unit
		2.7		6.5	12		
Ron	On-Resistance		3.3	-	6.0	10	Ω
			4.2		5.5	8	
	On-Resistance	$V_{10} = 0.2V_{10} 0.4V_{10}$	2.7		0.3	1.5	
Rflat	Flatness	$V_{IS} = 0.2V, 0.4V$ $I_{ON} = 8mA$	3.3	-	0.2	1	Ω
	Fiduless	$I_{ON} = OIIIA$	4.2		0.1	0.5	
	On-Resistance		2.7		0.25	0.5	
$\triangle R_{ON}$			3.3	-	0.2	0.45	Ω
	Matching		4.2		0.15	0.4	

High Speed On Resistance (Typical: $T_A = 25 \text{ °C}$, $V_{CC} = 3.3 \text{ V}$)

Full Speed On Resistance (Typical: $T_A = 25 \text{ °C}$, $V_{CC} = 3.3 \text{ V}$)

Symbol	Parameter	Test Conditions		-40	°C to +8	5°C	unit
Symbol	Farameter	Test Conditions	V _{cc} (V)	Min	Тур	Max	um
			2.7		9.0	13	
Ron	On-Resistance		3.3	-	7.5	11	Ω
		V _{IS} = 0.2V _{CC} ,0.5V _{CC} , 0.8V _{CC} , V _{CC}	4.2		6.0	9	
	On Desistance		2.7		0.5	0.8	
$\triangle R_{ON}$	On-Resistance	$I_{ON} = 8mA$	3.3	-	0.4	0.7	Ω
	Matching		4.2		0.3	0.6	
	On-Resistance	$V_{IS} = 0.2V, 0.4V,$	2.7		1.0	3	
Rflat	AT Flatness 0.7V,	0.7V,1.0V	3.3	-	0.5	1.5	Ω
		Flatness I _{ON} = 8mA			0.4	1.2	

AC Electrical Characteristics⁽²⁾

Timing / Frequency (Typical: $T_A = 25 \text{ °C}$, $V_{CC} = 3.3 \text{ V}$, $R_L = 50 \Omega$, $C_L = 5 \text{ pF}$, f = 1 MHz)

Symbol	Parameter	Test Conditions		-40	-40°C to +85°C			
Symbol	Parameter	rest conditions	V _{CC} (V)	Min	Тур	Max	unit	
ton	Turn-ON Time		2.7 ~ 4.5	-	14	20	ns	
toff	Turn-OFF Time		2.7 ~ 4.5	-	21	25	ns	
tввм	Break-Before-Make Delay	$V_{IS} = 0V$ to V_{CC}	2.7 ~ 4.5	2	8	-	ns	
BW	-3 dB Bandwidth	$C_L = 5pF$	2.7 ~ 4.5	-	550	-	MHz	
DVV		$C_L = 0 p F$	2.7 ~ 4.5	-	900	-		

Isolation (Typical: $T_A = 25$ °C, $V_{CC} = 3.3$ V, $R_L = 50 \Omega$, $C_L = 5 pF$, f = 1 MHz)

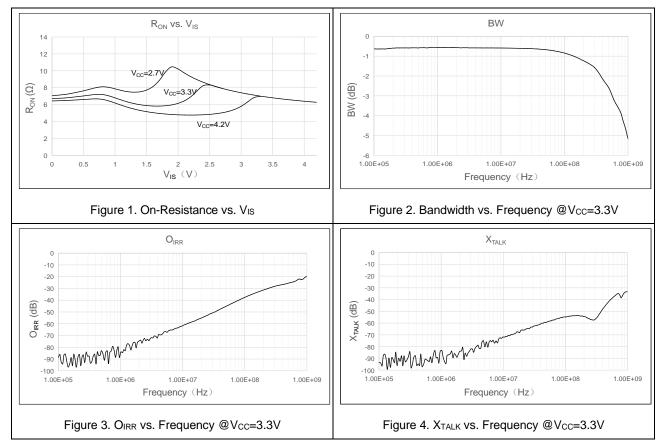
Symbol	Dino	Doromotor	Conditions	Conditions	Conditions	Conditions V _{cc} (V)	-40'	°C to +8	5°C	unit
Symbol	Pins	Parameter	Conditions		Min	Тур	Max	umi		
OIRR	Open	OFF-Isolation	f = 250MHz	1.65 ~ 4.5	-	-30	-	dB		
Xtalk	HSD1+ to HSD1-	Non-Adjacent Channel Crosstalk	f = 250MHz	1.65 ~ 4.5	-	-45	-	dB		

Capacitance (Typical: $T_A = 25 \text{ °C}$, $V_{CC} = 3.3 \text{ V}$, $R_L = 50 \Omega$, $C_L = 5 \text{ pF}$, f = 1 MHz)

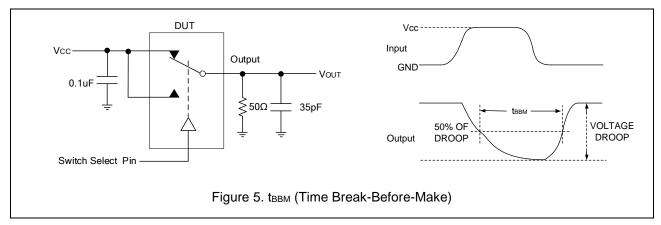
Symbol Pins		Parameter	Conditions	V., (\)	-40	°C to +8	5°C	unit
Symbol	FIIIS	Parameter	meter Conditions V _{CC} (V)		Min	Тур	Max	unit
C	12	Control Pin Input		0		2.0		ΣĽ
C _{IN} OE	Capacitance		0		2.0		pF	
C	D+ to	ON Capacitanas		2.2		0.0		~F
CON	HSD1/2+	ON Capacitance	$V_{OE}=0V$	3.3		8.0		pF
0	HSD2+,		Vis = 3.3V	2.2		2.5		~ F
Coff	HSD2-	OFF Capacitance	V _{OE} = 3.3V	3.3		3.5		pF

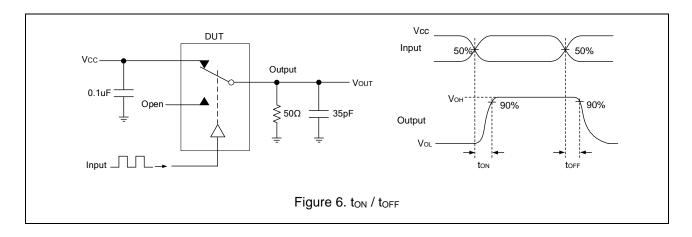
Note2: AC parameter is guaranteed by design.

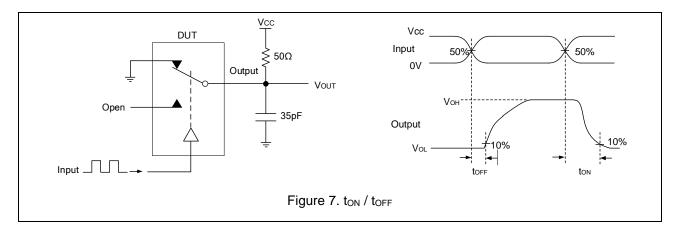
Typical Characteristics



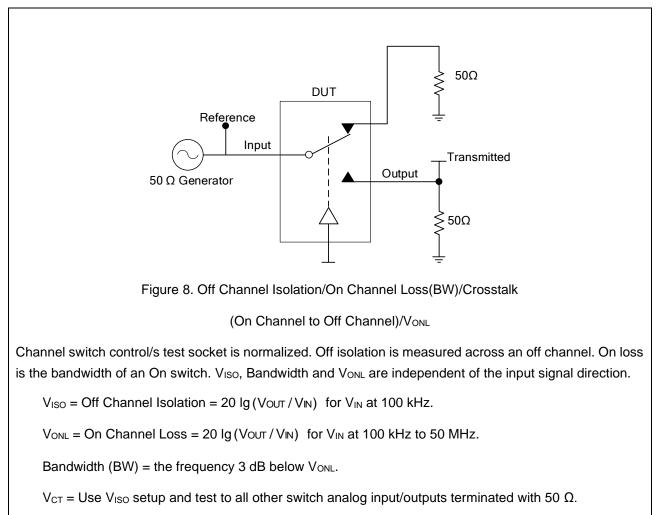
Test Circuit and Waveform





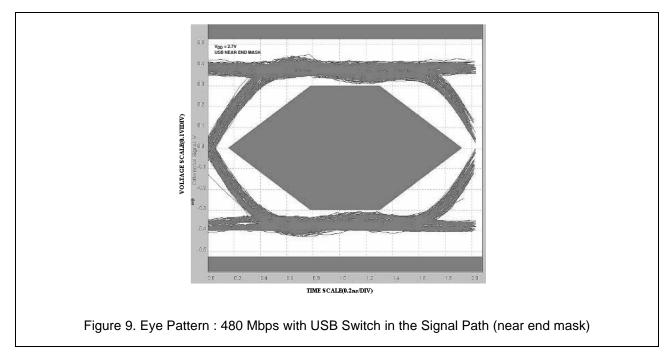


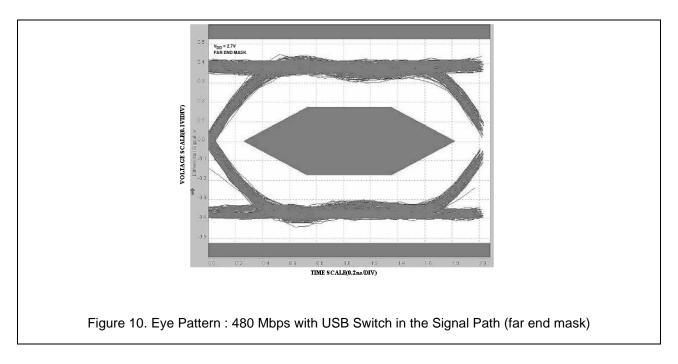
Test Circuit and Waveform(Continued)



Typical Performance Curves

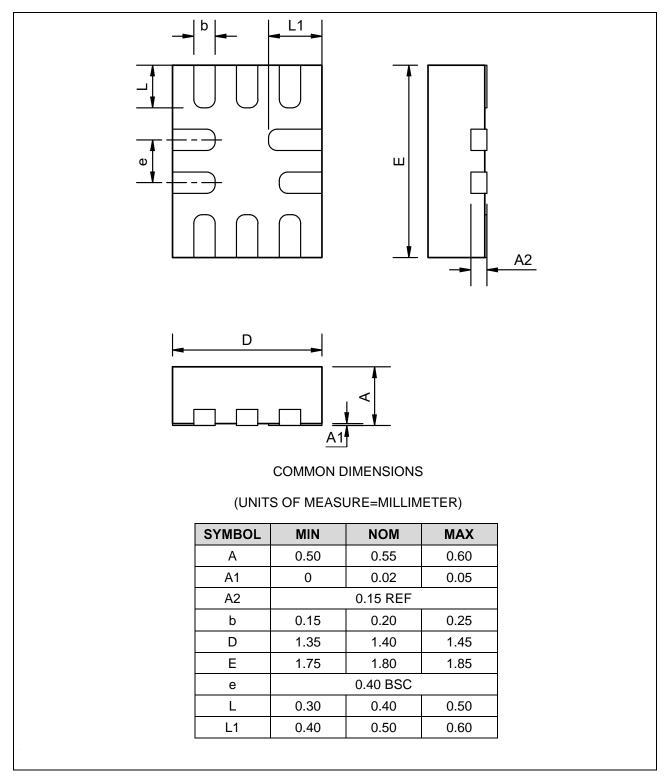
 T_A = +25 °C, Unless Otherwise Specified





Package Dimension

QFN10L



Revision History and Checking Table

Version	Date	Revision Item	Modifier	Function &	Package &
				Spec Checking	Tape Checking
1.0	2015-09-20	Original Version	Liu Xiao Min	Liu Xiao Min	Zhu Jun Li
1.1	2016-08-02	Update some parameters	Liu Xiao Min	Liu Xiao Min	Zhu Jun Li
1.2	2020-03-16	Documents check and formalize	Shib	Shib	Liujy
1.3	2022-11-15	Update Typeset and EC table	Qinpl	Qinpl	Liujy
1.4	2024-1-3	Add Tj	Shib	Shib	Liujy
1.5	2025-4-15	Update Typical Characteristics	Yinp	Yinp	Liujy